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| APPLICATION NO.               | FILING DATE        | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO. |  |
|-------------------------------|--------------------|----------------------|-------------------------|------------------|--|
| 10/779,557                    | 02/06/2004         | Franz Hofmann        | 20046/0200847-US0       | 9018             |  |
| 7278 75                       | 90 06/03/2005      | 06/03/2005           |                         | EXAMINER         |  |
| DARBY & DARBY P.C.            |                    |                      | SOWARD, IDA M           |                  |  |
| P. O. BOX 5257<br>NEW YORK, 1 | 7<br>NY 10150-5257 |                      | ART UNIT                | PAPER NUMBER     |  |
| ,                             |                    |                      | 2822                    |                  |  |
|                               |                    |                      | DATE MAILED: 06/03/2009 | 5                |  |

Please find below and/or attached an Office communication concerning this application or proceeding.

|  | <del></del>  |  |  |  |  |
|--|--|--|--|--|--|
|  | Application No.  | Applicant(s)   |  |  |  |
|  | 10/779,557   | HOFMANN ET AL.   |  |  |  |
| Office Action Summary  | Examiner   | Art Unit   |  |  |  |
|  | Ida M. Soward  | 2822   |  |  |  |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply   |  |  |  |  |  |
| A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). | 36(a). In no event, however, may a reply be tim<br>y within the statutory minimum of thirty (30) day<br>will apply and will expire SIX (6) MONTHS from<br>to cause the application to become ABANDONE  | nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133). |  |  |  |
| Status   |  |  |  |  |  |
| 1) Responsive to communication(s) filed on 06 F  | ebruary 2004.  |  |  |  |  |
| 2a) This action is <b>FINAL</b> . 2b) This   | <u> </u>   |  |  |  |  |
| 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.   |  |  |  |  |  |
| Disposition of Claims  |  |  |  |  |  |
| 4) ⊠ Claim(s) 1-11 is/are pending in the application 4a) Of the above claim(s) is/are withdray 5) ⊠ Claim(s) 1-10 is/are allowed. 6) ⊠ Claim(s) 11 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and/or  | wn from consideration.   |  |  |  |  |
| Application Papers   |  | ·  |  |  |  |
| 9) The specification is objected to by the Examine 10) The drawing(s) filed on 06 February 2004 is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Example 11.  | e: a) $\boxtimes$ accepted or b) $\square$ objecte drawing(s) be held in abeyance. Settion is required if the drawing(s) is ob-  | e 37 CFR 1.85(a).<br>jected to. See 37 CFR 1.121(d).   |  |  |  |
| Priority under 35 U.S.C. § 119   |  |  |  |  |  |
| 12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the prio application from the International Burear * See the attached detailed Office action for a list   | is have been received. Is have been received in Application in the second in the secon | ion No<br>ed in this National Stage  |  |  |  |
| Attachment(s)  | n □  | (DTO 442)  |  |  |  |
| <ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)<br/>Paper No(s)/Mail Date 3-10-04.</li> </ol>   | 4)  Interview Summary Paper No(s)/Mail Di 5)  Notice of Informal F 6)  Other:  |  |  |  |  |

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#### **DETAILED ACTION**

This Office Action is in response to the application filed February 6, 2004.

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claim 11 is rejected under 35 U.S.C. 102(e) as being anticipated by Chen et al. (US 6,504,207 B1).

Chen et al. teach a memory cell 500 comprising: a substrate; a source region 515 formed in the substrate; a drain region 516 formed in the substrate; a source-end control gate 556 extending at least partially over the source region 515; a drain-end control gate 555 extending at least partially over the drain region 516; an injection gate 554 arranged between the source-end control gate 556 and the drain-end control gate 555; a source-end storage element arranged in the source-end control gate 556; and a drain-end storage element arranged in the drain-end control gate 555 (Figure 5, column 5, lines 23-43), wherein the memory cell is programmed by applying a first electrical voltage —12V to the injection gate 554 and a second electrical voltage GND to the

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control gates 555 & 556 (Figure 5, column 5, lines 23-43), the second electrical voltage 1.8V having a greater absolute value than the first electrical voltage 0V (Figure 8).

### Allowable Subject Matter

Claims 1-10 are allowed.

The following is an examiner's statement of reasons for allowance: The prior art of record does not disclose, make obvious, or otherwise suggest the structure of the applicant's together with the other limitations of the independent claims, such as "a channel region provided between the source region and the drain region and having a variable electrical conductivity; and a gate oxide arrangement having at least one gate oxide layer extending between the substrate on the one side and the source-end control gate, the drain-end control gate and the injection gate on the other side, wherein the source-end control gate and the drain-end control gate are electrically connected to one another".

The dependent claims being further limiting and definite are also allowable.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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#### Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

The following patents are cited to further show the state of the art with respect to memory cells:

| Chang et al. (US 6,291,855 B1) | Hsieh et al. (US 6,228,695 B1)  |
|--------------------------------|---------------------------------|
| Jenq (6,057,575)               | Kelley et al. (US 6,313,500 B1) |
| Liang et al. (US 6,281,545 B1) | Manley (5,284,784)              |
| Merrill (5,900,657)            | Sung et al. (US 6,331,721 B1)   |
| Uchida (4,907,197)             | Uenoyama et al. (5,973,357)     |
| Vasché (5,977,585)             | Yamazaki et al. (5,633,519).    |

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ida M. Soward whose telephone number is 571-272-1845. The examiner can normally be reached on Monday - Thursday 6:30am to 5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

**IMS** 

May 25, 2005